

Zibo Seno Electronic Engineering Co., Ltd.



D25XB05-D25XB100



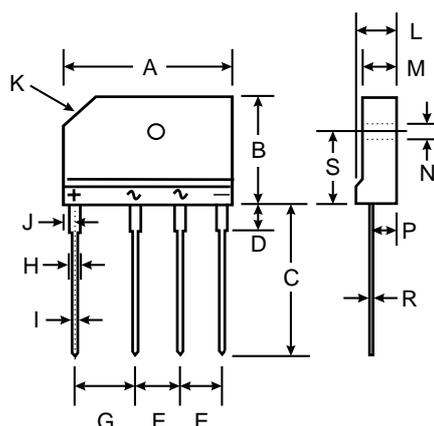
25A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1500V_{RMS}
- Low Reverse Leakage Current
- Surge Overload Rating to 350A Peak
- Ideal for Printed Circuit Board Applications
- Plastic Material - UL Flammability Classification 94V-0
- Lead Free Finish/RoHS Compliant

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Polarity: Molded on Body
- Mounting: Through Hole for #6 Screw
- Mounting Torque: 5.0 in-lbs Maximum
- Weight: 6.6 grams (approx)
- Marking: Type Number



5S		
Dim	Min	Max
A	29.70	30.30
B	19.70	20.30
C	17.00	18.00
D	3.80	4.20
E	7.30	7.70
G	9.80	10.20
H	2.00	2.40
I	0.90	1.10
J	2.30	2.70
K	3.0 X 45°	
L	4.40	4.80
M	3.40	3.80
N	3.10	3.40
P	2.50	2.90
R	0.60	0.80
S	10.80	11.20
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	D25XB 05	D25XB 10	D25XB 20	D25XB 20	D25XB 60	D25XB 80	D25XB 100	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V _{RWM}								
DC Blocking Voltage	V _R								
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Forward Rectified Output Current (Note 1)	I _O				25				A
		@ T _C = 100°C							
Non-Repetitive Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}				350				A
Forward Voltage (per element)	V _{FM}				1.05				V
		@ I _F = 12.5A							
Peak Reverse Current	I _R				10				μA
		at Rated DC Blocking Voltage							
		@ T _C = 25°C							
		@ T _C = 125°C							
I ² t Rating for Fusing (t < 8.3ms) (Note 1)	I ² t				510				A ² s
Typical Junction Capacitance (per element) (Note 2)	C _j				85				pF
Typical Thermal Resistance Junction to Case (Note 3)	R _{θJC}				0.6				°C/W
Operating and Storage Temperature Range	T _j , T _{STG}				-65 to +150				°C

- Notes:
1. Non-repetitive, for t > 1ms and < 8.3 ms.
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
 3. Thermal resistance from junction to case per element. Unit mounted on 220 x 220 x 1.6mm aluminum plate heat sink.